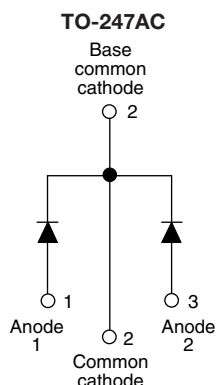
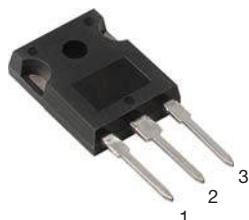


HEXFRED® **Ultrafast Soft Recovery Diode, 2 x 25 A**



FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC-JESD47
- Material categorization:
For definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
Available

BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA50PA60C... is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 25 A per leg continuous current, the VS-HFA50PA60C... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to “snap-off” during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA50PA60C... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

PRODUCT SUMMARY

Package	TO-247AC
$I_{F(AV)}$	2 x 25 A
V_R	600 V
V_F at I_F	1.7 V
t_{rr} typ.	23 ns
T_J max.	150 °C
Diode variation	Common cathode

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	V_R		600	V
Maximum continuous forward current	I_F	$T_C = 100\text{ °C}$	25	A
per leg			50	
per device				
Single pulse forward current	I_{FSM}		225	
Maximum repetitive forward current	I_{FRM}		100	
Maximum power dissipation	P_D	$T_C = 25\text{ °C}$	150	W
		$T_C = 100\text{ °C}$	60	
Operating junction and storage temperature range	T_J, T_{Stg}		- 55 to + 150	°C



ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX. UNITS
Cathode to anode breakdown voltage	V_{BR}	$I_R = 100\text{ }\mu\text{A}$		600	-	-
Maximum forward voltage	V_{FM}	$I_F = 25\text{ A}$	See fig. 1	-	1.3	1.7
		$I_F = 50\text{ A}$		-	1.5	2.0
		$I_F = 25\text{ A}, T_J = 125\text{ }^{\circ}\text{C}$		-	1.3	1.7
Maximum reverse leakage current	I_{RM}	$V_R = V_R\text{ rated}$	See fig. 2	-	1.5	20
		$T_J = 125\text{ }^{\circ}\text{C}, V_R = 0.8 \times V_R\text{ rated}$		-	600	2000
Junction capacitance	C_T	$V_R = 200\text{ V}$	See fig. 3	-	55	100
Series inductance	L_S	Measured lead to lead 5 mm from package body		-	12	-

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX. UNITS
Reverse recovery time See fig. 5, 10	t_{rr}	$I_F = 1.0\text{ A}, dI_F/dt = 200\text{ A}/\mu\text{s}, V_R = 30\text{ V}$		-	23	-
	t_{rr1}	$T_J = 25\text{ }^{\circ}\text{C}$	$I_F = 25\text{ A}$ $dI_F/dt = 200\text{ A}/\mu\text{s}$ $V_R = 200\text{ V}$	-	50	75
	t_{rr2}	$T_J = 125\text{ }^{\circ}\text{C}$		-	105	160
Peak recovery current See fig. 6	I_{RRM1}	$T_J = 25\text{ }^{\circ}\text{C}$		-	4.5	10
	I_{RRM2}	$T_J = 125\text{ }^{\circ}\text{C}$		-	8.0	15
Reverse recovery charge See fig. 7	Q_{rr1}	$T_J = 25\text{ }^{\circ}\text{C}$		-	112	375
	Q_{rr2}	$T_J = 125\text{ }^{\circ}\text{C}$		-	420	1200
Peak rate of fall of recovery current during t_b See fig. 8	$dI_{(rec)M}/dt1$	$T_J = 25\text{ }^{\circ}\text{C}$		-	250	-
	$dI_{(rec)M}/dt2$	$T_J = 125\text{ }^{\circ}\text{C}$		-	160	-

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T_{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	$^{\circ}\text{C}$
Junction to case, single leg conducting	R_{thJC}		-	-	0.83	K/W
Junction to case, both legs conducting			-	-	0.42	
Thermal resistance, junction to ambient	R_{thJA}	Typical socket mount	-	-	40	
Thermal resistance, case to heatsink	R_{thCS}	Mounting surface, flat, smooth and greased	-	0.25	-	
Weight			-	6.0	-	g
			-	0.21	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC	HFA50PA60C			

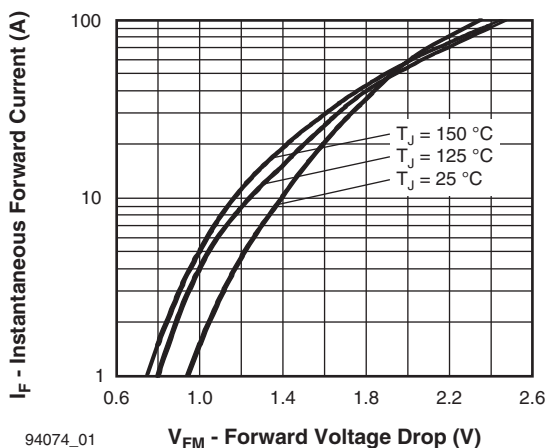


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

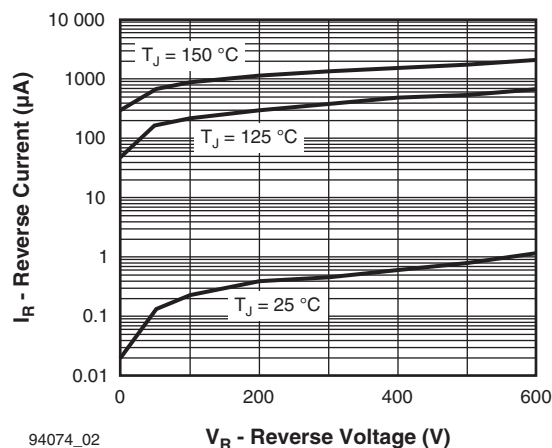


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

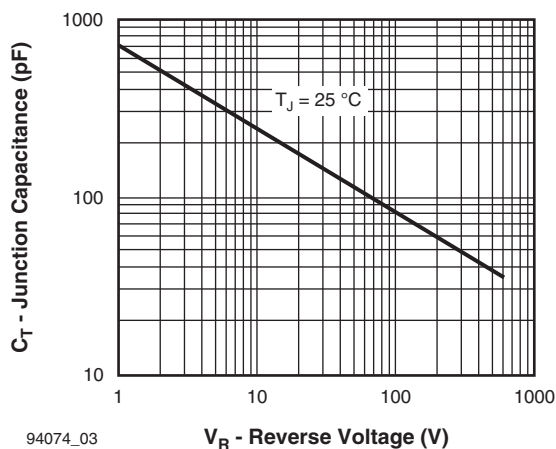


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

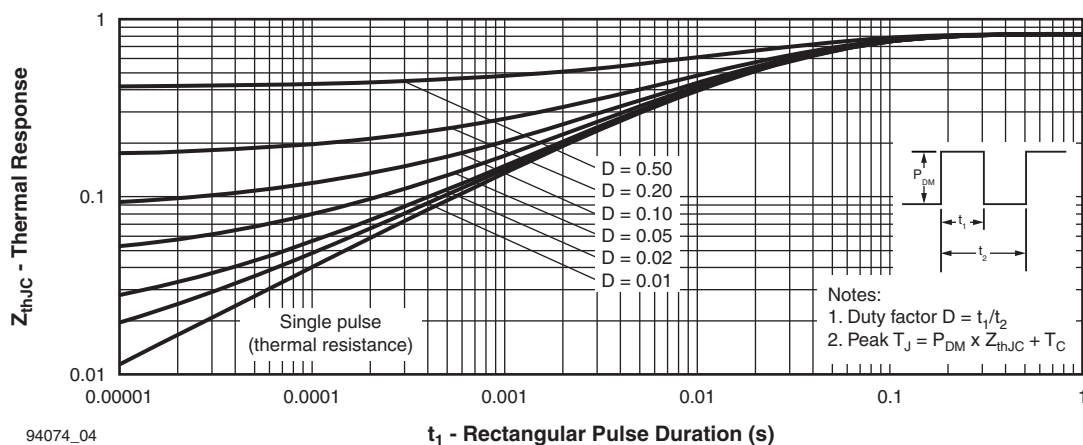
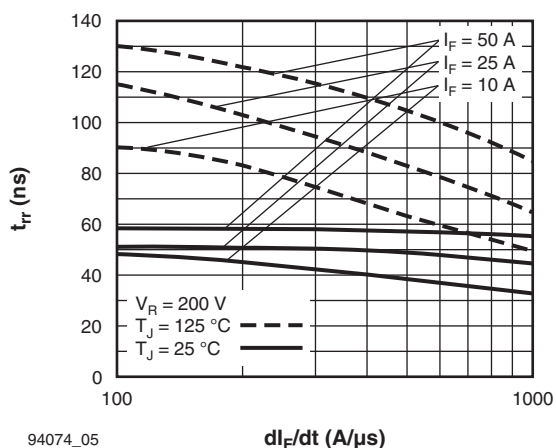
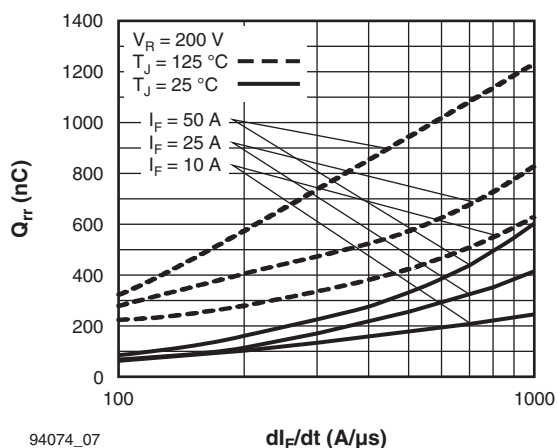


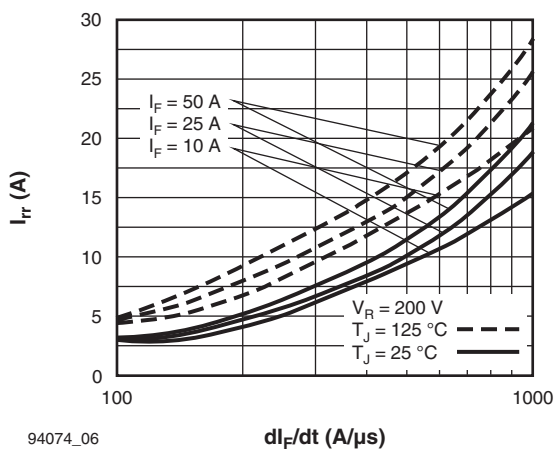
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)



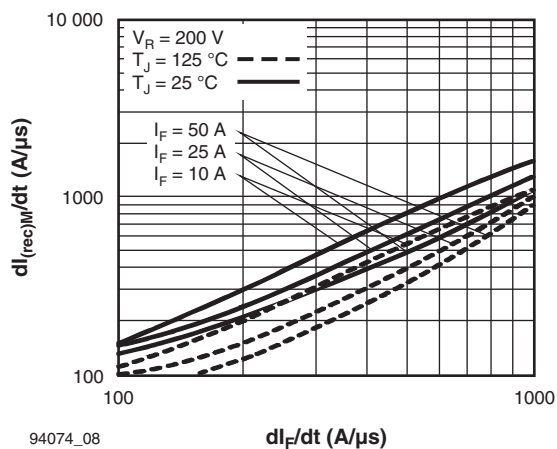
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Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt (Per Leg)


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Fig. 7 - Typical Stored Charge vs. dI_F/dt (Per Leg)


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Fig. 6 - Typical Recovery Current vs. dI_F/dt (Per Leg)


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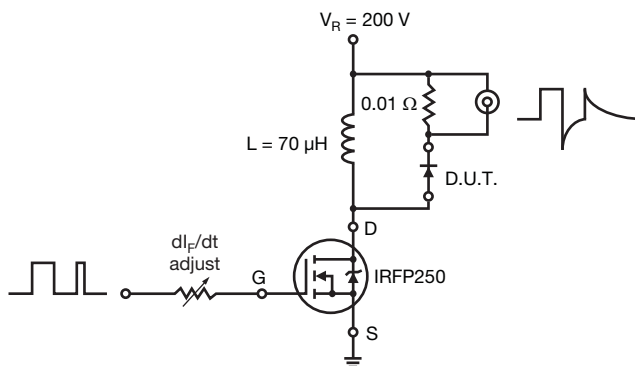
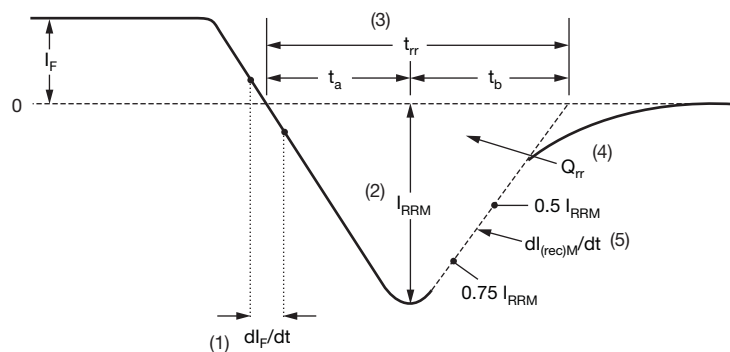
Fig. 8 - Typical dI_{recM}/dt vs. dI_F/dt (Per Leg)


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dI_F/dt - rate of change of current through zero crossing
- (2) I_{RRM} - peak reverse recovery current
- (3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current.
- (4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}
- (5) $dI_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

Fig. 10 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code	VS-	HF	A	50	PA	60	C	PbF
	1	2	3	4	5	6	7	8

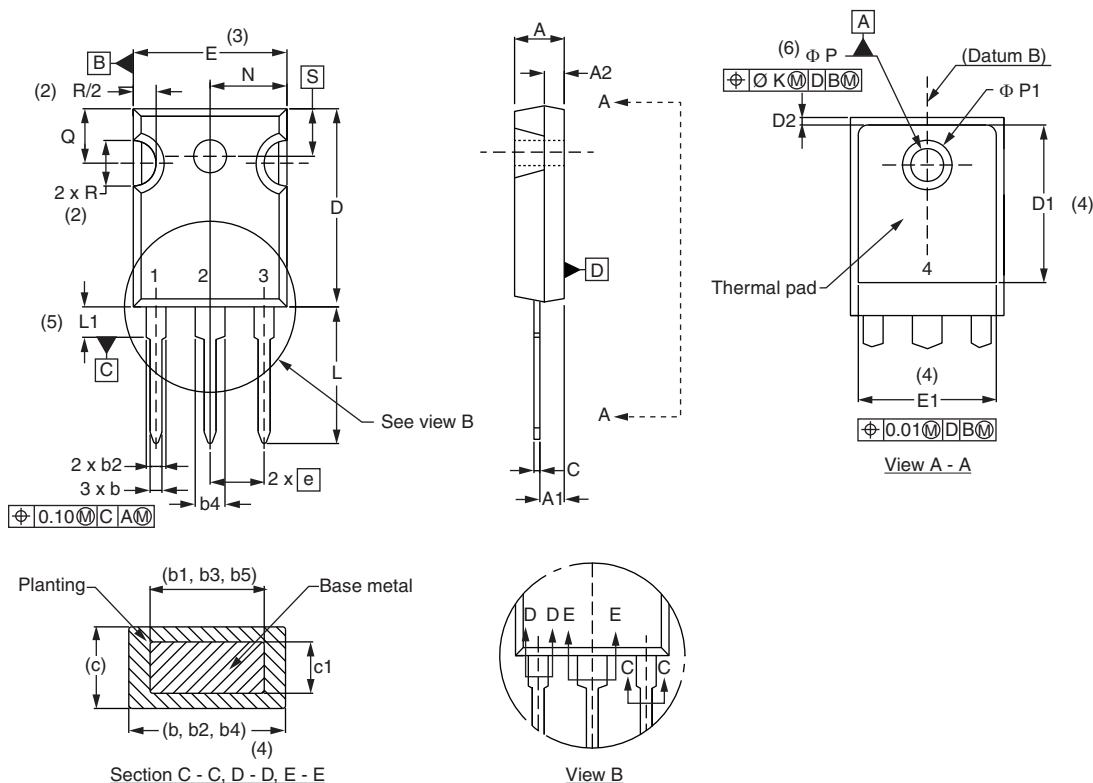
- 1** - Vishay Semiconductors product
- 2** - HEXFRED® family
- 3** - Electron irradiated
- 4** - Current rating (50 = 50 A)
- 5** - PA = TO-247AC
- 6** - Voltage rating: (60 = 600 V)
- 7** - Circuit configuration
C = Common cathode
- 8** - Environmental digit:
PbF = Lead (Pb)-free and RoHS compliant
-N3 = Halogen-free, RoHS compliant and totally lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-HFA50PA60CPbF	25	500	Antistatic plastic tube
VS-HFA50PA60C-N3	25	500	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS			
Dimensions			www.vishay.com/doc?95542
Part marking information	TO-247ACPbF		www.vishay.com/doc?95226
	TO-247AC-N3		www.vishay.com/doc?95007

TO-247

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.17	1.37	0.046	0.054	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.33	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
c	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
D2	0.51	1.35	0.020	0.053	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
e	5.46 BSC		0.215 BSC		
Ø K	0.254		0.010		
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62 BSC		0.3		
Ø P	3.56	3.66	0.14	0.144	
Ø P1	-	7.39	-	0.291	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

Notes

- Dimensioning and tolerancing per ASME Y14.5M-1994
- Contour of slot optional
- Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Thermal pad contour optional with dimensions D1 and E1
- Lead finish uncontrolled in L1
- Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



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